Diode Semiconductor Device - Page 1 of 1

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Inclosure Material:
Glass
Overall Length:
Between 0.075 inches and 0.097 inches
Overall Diameter:
Between 0.118 inches and 0.124 inches
End Application:
19905-tu-511p
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
60.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
10.00 microamperes forward current, total rms any acceptable
Special Features:
Total capacitance 15.0 (at-4v, 1 mhz) ct-4 (pf)
Terminal Type And Quantity:
2 ferrule
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0